

Bias Resistor Transistor

PNP Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

- Applications

Inverter, Interface, Driver

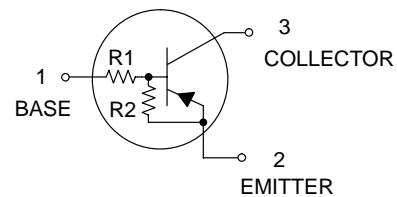
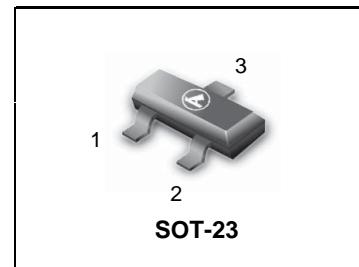
- Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
 - 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
 - 3) Only the on / off conditions need to be set for operation, making the device design easy.
- We declare that the material of product compliance with RoHS requirements.
 - S - Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

- **Absolute maximum ratings (Ta=25°C)**

Parameter	Symbol	Limits		Unit
Supply voltage	V _{cc}	-50		V
Input voltage	V _{IN}	-30 to +10		V
Output current	I _c	-500		mA
Power dissipation	P _D	200		mW
Junction temperature	T _j	150		°C
Storage temperature	T _{stg}	-55 to +150		°C

**LDTB143ELT1G
S-LDTB143ELT1G**



DEVICE MARKING AND RESISTOR VALUES

Device	Marking	R1 (K)	R2 (K)	Shipping
LDTB143ELT1G S-LDTB143ELT1G	K6	4.7	4.7	3000/Tape & Reel
LDTB143ELT3G S-LDTB143ELT3G	K6	4.7	4.7	10000/Tape & Reel

- **Electrical characteristics (Ta=25°C)**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V _{I(off)}	—	—	-0.5	V	V _{cc} = -5V, I _o = -100μA
	V _{I(on)}	-3	—	—	V	V _o = -0.3V, I _o = -20mA
Output voltage	V _{O(on)}	—	-0.1	-0.3	V	I _o /I _l = -50mA/-2.5mA
Input current	I _l	—	—	-1.8	mA	V _i = -5V
Output current	I _{o(off)}	—	—	-0.5	μA	V _{cc} = -50V, V _i =0V
DC current gain	G _i	47	—	—	—	V _o = -5V, I _o = -50mA
Input resistance	R ₁	3.29	4.7	6.11	kΩ	—
Resistance ratio	R ₂ /R ₁	0.8	1	1.2	—	—
Transition frequency	f _t *	—	200	—	MHz	V _{ce} = -10V, I _e =50mA, f=100MHz

* Characteristics of built-in transistors

LDTB143ELT1G ;S-LDTB143ELT1G

●Electrical characteristic curves

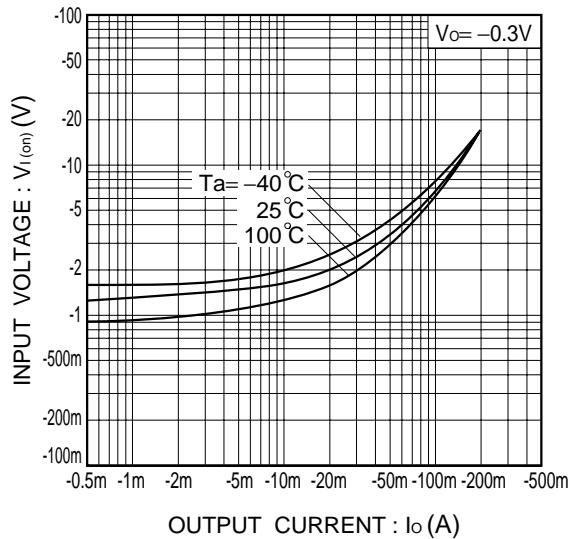


Fig.1 Input voltage vs. output current

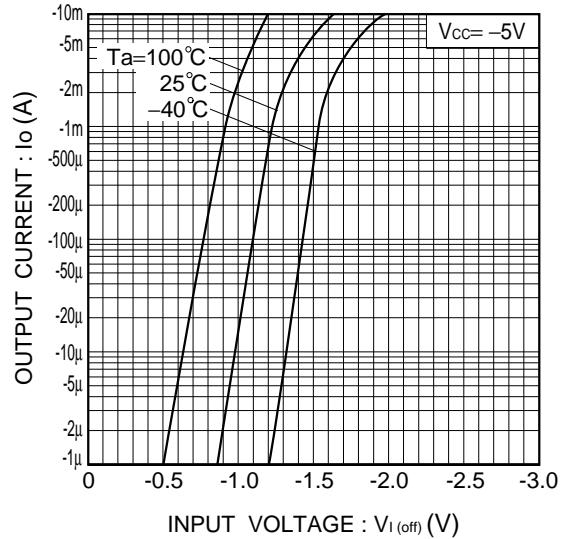


Fig.2 Output current vs. input voltage (OFF characteristics)

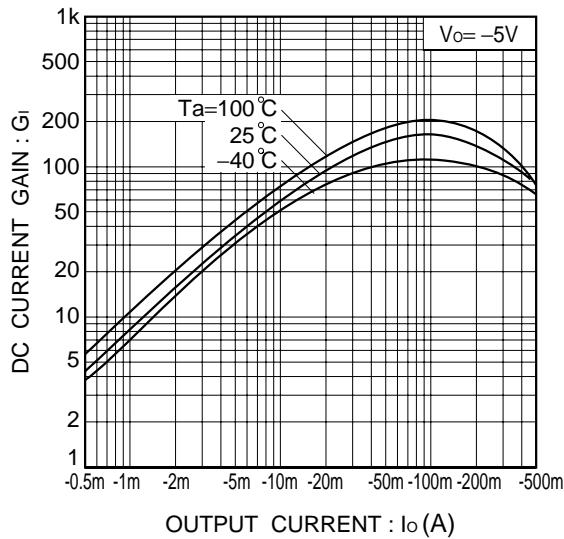


Fig.3 DC current gain vs. output current

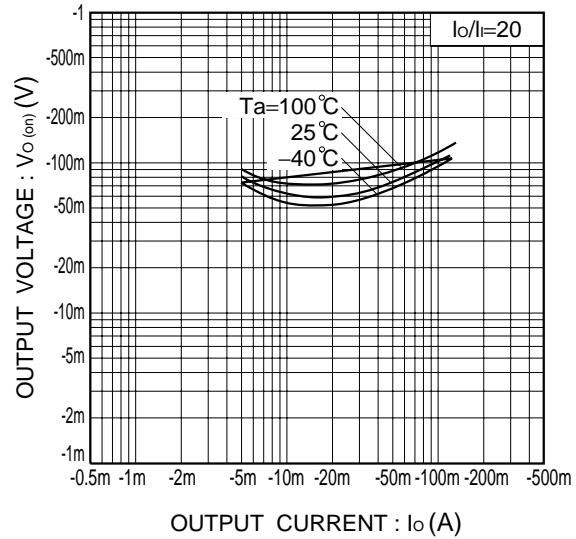
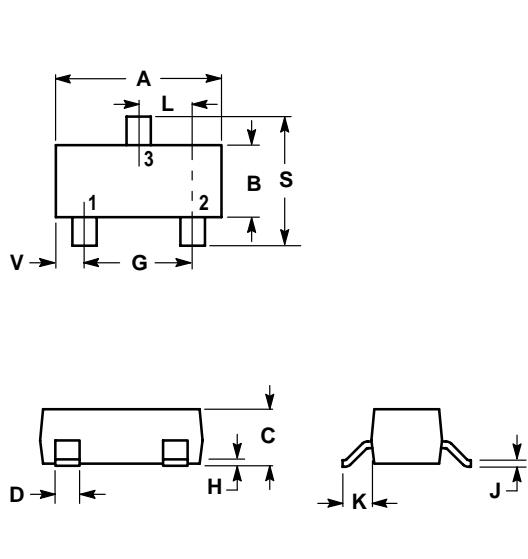


Fig.4 Output voltage vs. output current

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NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

